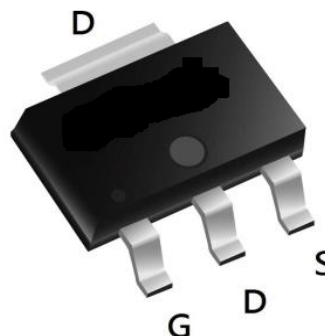


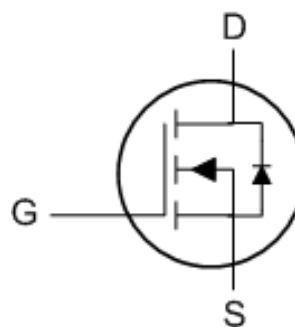
### General Description

These logic level N-Channel enhancement This very high density process is especially tailored to minimize on-state resistance and provide superior switching performance, and withstand high energy pulse in the avalanche and commutation modes. These devices are particularly suited for low voltage applications such as DC motor control and DC/DC conversion where fast switching, low in-line power loss, and resistance to transients are needed.



### Features

- $V_{DS} (V) = 60V$
- $R_{DS(ON)} < 100m\Omega$  ( $V_{GS} = 10V$ )
- $R_{DS(ON)} < 50m\Omega$  ( $V_{GS} = 4.5V$ )
- Low drive requirements allowing operation directly from logic drivers.  $V_{GS(TH)} < 2V$ .
- High density cell design for extremely low  $R_{DS(ON)}$ .
- High power and current handling capability in a widely used surface mount package.



### Absolute Maximum Ratings $T_A = 25^\circ C$ unless otherwise noted

Symbol	Parameter	IRFL4105	Units
$V_{DSS}$	Drain-Source Voltage	60	V
$V_{GSS}$	Gate-Source Voltage - Continuous	$\pm 20$	V
$I_D$	Maximum Drain Current - Continuous (Note 1a)	4	A
	- Pulsed	25	
$P_D$	Maximum Power Dissipation (Note 1a)	3	W
	(Note 1b)	1.3	
	(Note 1c)	1.1	
$T_J, T_{STG}$	Operating and Storage Temperature Range	-65 to 150	$^\circ C$
<b>THERMAL CHARACTERISTICS</b>			
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 1a)	42	$^\circ C/W$
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case (Note 1)	12	$^\circ C/W$

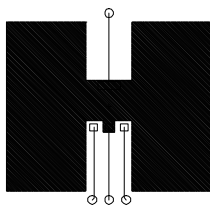
\* Order option J23Z for cropped center drain lead.

**Electrical Characteristics** ( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted )

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>OFF CHARACTERISTICS</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	60			V
$\Delta BV_{DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient	$I_D = 250\text{ }\mu\text{A}$ , Referenced to $25\text{ }^\circ\text{C}$		55		$\text{mV}/^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 60\text{ V}, V_{GS} = 0\text{ V}$ $T_J = 125\text{ }^\circ\text{C}$			1	$\mu\text{A}$
					50	$\mu\text{A}$
$I_{GSSF}$	Gate - Body Leakage, Forward	$V_{GS} = 20\text{ V}, V_{DS} = 0\text{ V}$			100	nA
$I_{GSSR}$	Gate - Body Leakage, Reverse	$V_{GS} = -20\text{ V}, V_{DS} = 0\text{ V}$			-100	nA
<b>ON CHARACTERISTICS</b> (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1	1.6	2	V
$\Delta V_{GS(th)}/\Delta T_J$	Gate Threshold Voltage Temp. Coefficient	$I_D = 250\text{ }\mu\text{A}$ , Referenced to $25\text{ }^\circ\text{C}$		-4		$\text{mV}/^\circ\text{C}$
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10\text{ V}, I_D = 4\text{ A}$ $V_{GS} = 4.5\text{ V}, I_D = 3.7\text{ A}$		70	100	m $\Omega$
				103	120	
$I_{D(on)}$	On-State Drain Current	$V_{GS} = 5\text{ V}, V_{DS} = 10\text{ V}$	10			A
$g_{FS}$	Forward Transconductance	$V_{DS} = 5\text{ V}, I_D = 4\text{ A}$		7		S
<b>DYNAMIC CHARACTERISTICS</b>						
$C_{iss}$	Input Capacitance	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$		345		pF
$C_{oss}$	Output Capacitance			110		pF
$C_{rss}$	Reverse Transfer Capacitance			30		pF
<b>SWITCHING CHARACTERISTICS</b> (Note 2)						
$t_{D(on)}$	Turn - On Delay Time	$V_{DD} = 25\text{ V}, I_D = 1\text{ A},$ $V_{GS} = 10\text{ V}, R_{GEN} = 6\text{ }\Omega$		5	20	ns
$t_r$	Turn - On Rise Time			7.5	20	ns
$t_{D(off)}$	Turn - Off Delay Time			20	50	ns
$t_f$	Turn - Off Fall Time			7	20	ns
$Q_g$	Total Gate Charge	$V_{DS} = 40\text{ V}, I_D = 4\text{ A},$ $V_{GS} = 10\text{ V}$		13	20	nC
$Q_{gs}$	Gate-Source Charge			1.7		nC
$Q_{gd}$	Gate-Drain Charge			3.2		nC
<b>DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS</b>						
$I_S$	Maximum Continuous Drain-Source Diode Forward Current				2.5	A
$V_{SD}$	Drain-Source Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = 2.5\text{ A}$ (Note 2)		0.8	1.2	V

Notes:

- $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a.  $42^\circ\text{C}/\text{W}$  when mounted on a  $1\text{ in}^2$  pad of 2oz Cu.



b.  $95^\circ\text{C}/\text{W}$  when mounted on a  $0.066\text{ in}^2$  pad of 2oz Cu.

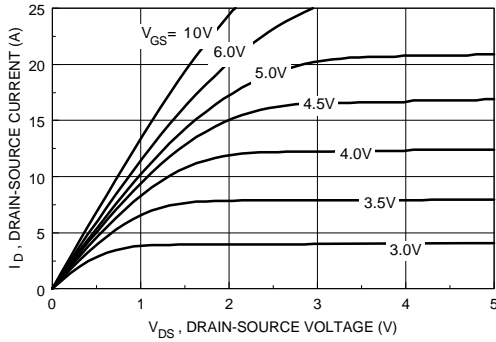


c.  $110^\circ\text{C}/\text{W}$  when mounted on a  $0.00123\text{ in}^2$  pad of 2oz Cu.

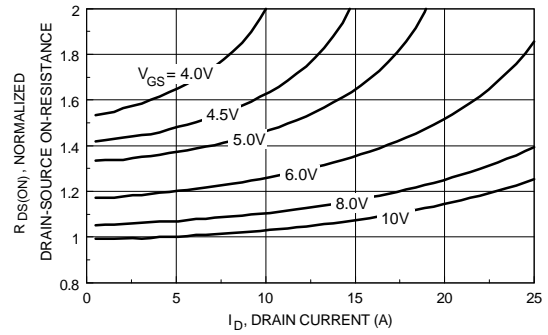
Scale 1 : 1 on letter size paper

- Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

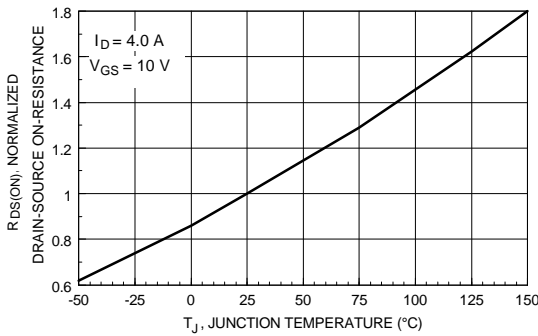
**Typical Electrical Characteristics**



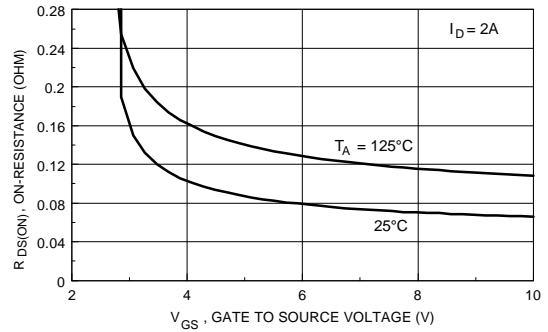
**Figure 1. On-Region Characteristics.**



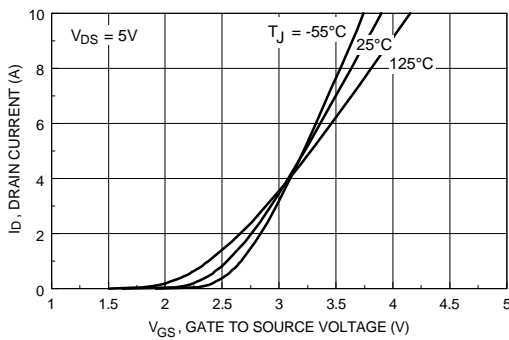
**Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.**



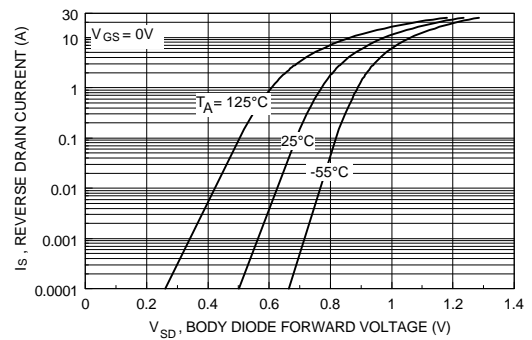
**Figure 3. On-Resistance Variation with Temperature.**



**Figure 4. On-Resistance Variation with Gate-to-Source Voltage.**

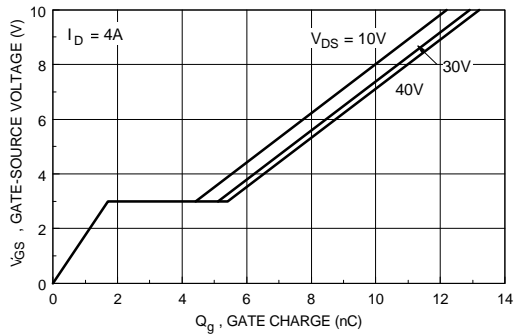


**Figure 5. Transfer Characteristics.**

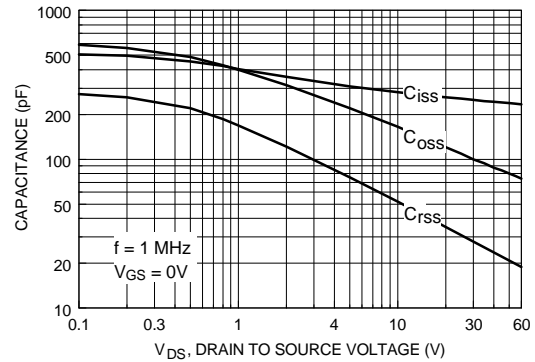


**Figure 6. Body Diode Forward Voltage Variation with Current and Temperature.**

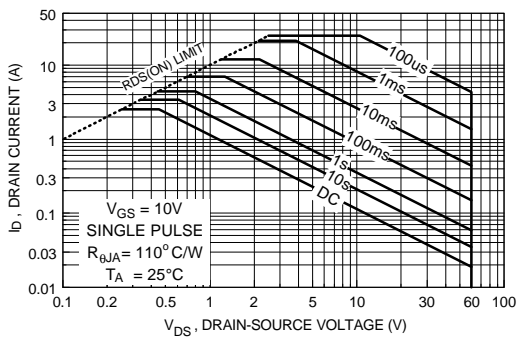
**Typical Electrical Characteristics (continued)**



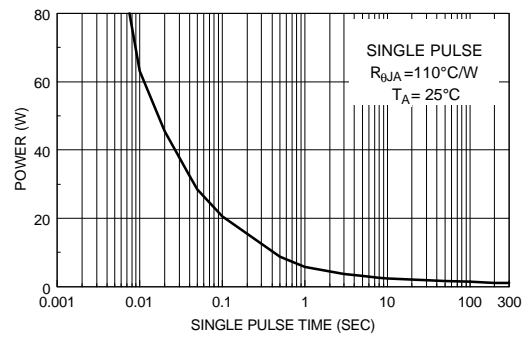
**Figure 7. Gate Charge Characteristics.**



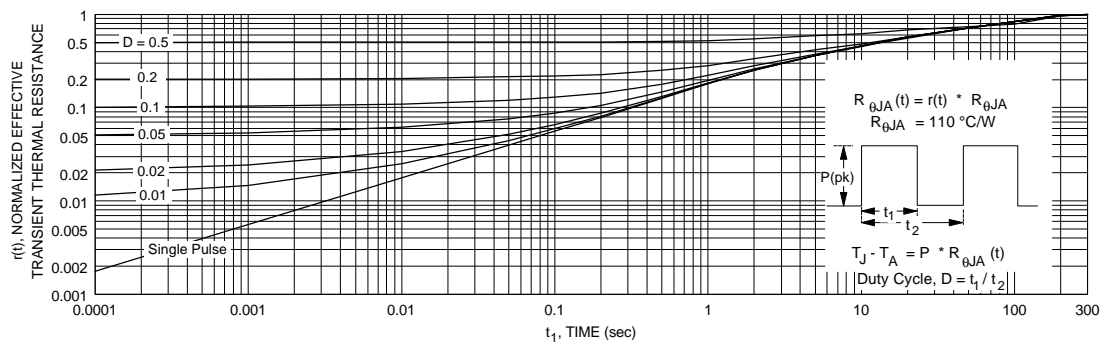
**Figure 8. Capacitance Characteristics.**



**Figure 9. Maximum Safe Operating Area.**



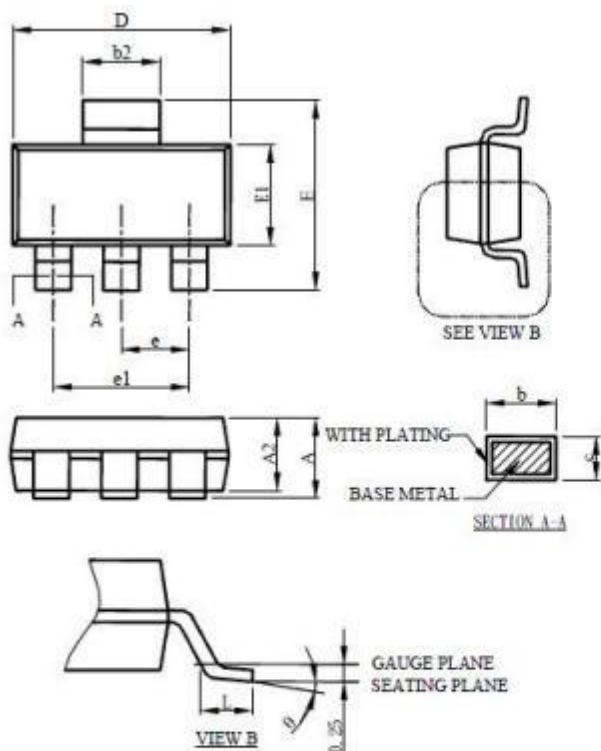
**Figure 10. Single Pulse Maximum Power Dissipation.**



**Figure 11. Transient Thermal Response Curve.**

Thermal characterization performed using the conditions described in note 1c.  
Transient thermal response will change depending on the circuit board design.

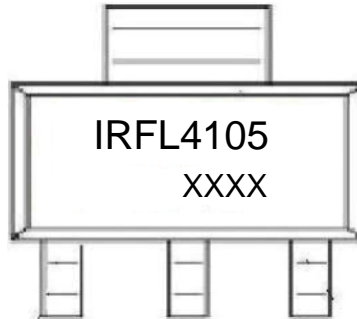
**SOT-223**



SYMBOL	SOT-223	
	MILLIMETERS	
	MIN.	MAX.
A		1.80
A1	0.02	0.10
A2	1.55	1.65
b	0.86	0.84
b2	2.90	3.10
c	0.23	0.33
D	6.30	6.70
E	6.70	7.30
E1	3.30	3.70
e	2.30 BSC	
e1	4.60 BSC	
L	0.90	
θ	0°	8°

- Note:
1. Refer to JEDEC TO-261AA.
  2. Dimension D and E1 are determined at the outermost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs, and interlead flash, but including any mismatch between the top and bottom of the plastic body.
  3. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

**Marking**



**Ordering information**

<b>Order code</b>	<b>Package</b>	<b>Baseqty</b>	<b>Deliverymode</b>
IRFL4105	SOT-223	2500	Tape and reel